NSN 5962-01-413-2471

Memory Microcircuit - Page 1 of 1

Time Rating Per Chacteristic:

Terminal Type And Quantity:

Memory Device Type:

Special Features:

memory eprom

Unit Of Measure:

Demilitarization:

Eprom

32 pin
Shelf Life:

N/a

No Fiig: A458a0

120.00 nanoseconds propagation delay



View Online at https://aerobasegroup.com/nsn/5962-01-413-2471 **Operating Tempurature Range:** +0.0/+70.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** P/n an/2fsc-109, scis (sunwable communications integration sys) **Features Provided:** Electrostatic sensitive and ultraviolet erasable and programmable and high speed **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Criticality Code Justification:** Cbbl **Current Rating Per Characteristic:** 30.00 milliamperes forward current, nonrepetitive, peak total value absolute **Product Name:** Cmos 1 megabit (128k x 8) uv eprom and otp rom **Voltage Rating And Type Per Characteristic:** -0.6 volts total supply and 7.0 volts total supply

Part of cca, p/n mvme1475-1; usedon mx-11534/u demultiplexer, p/n 03-06236-001; 1 megabit uv erasable and electrically programmable